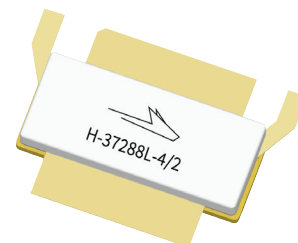


PTFB092707FH

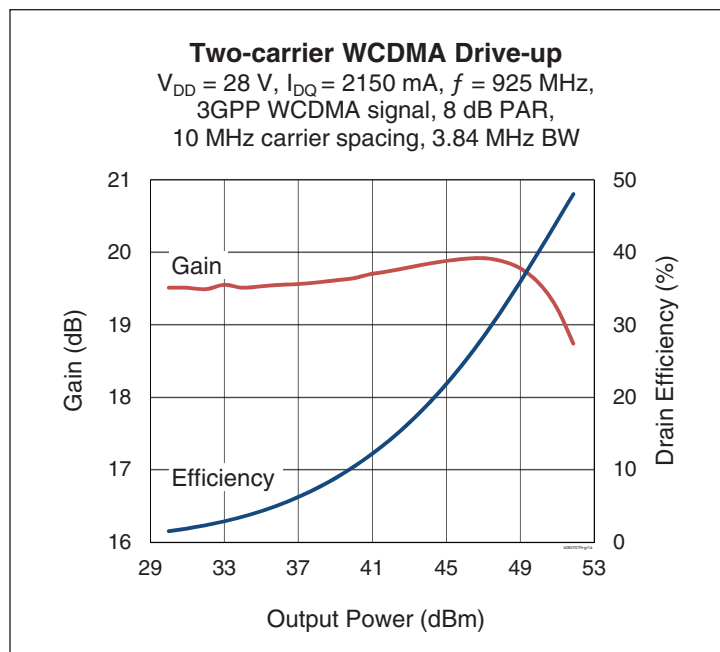
Thermally-Enhanced High Power RF LDMOS FET 270 W, 28 V, 925 – 960 MHz

Description

The PTFB092707FH is a 270-watt LDMOS FET intended for use in multi-standard cellular power amplifier applications in the 925 to 960 MHz frequency band. Features include input and output matching, high gain and thermally-enhanced package with earless flange. Manufactured with Wolfspeed's advanced LDMOS process, this device provides excellent thermal performance and superior reliability.



PTFB092707FH
Package H-37288L-4/2



Features

- Broadband internal input and output matching
- Typical pulsed CW performance (10 μs pulse width 10%, duty cycle, class AB), 960 MHz, 28 V
 - Output power at $P_{1\text{dB}} = 250\text{ W}$
 - Efficiency = 52%
 - Gain = 18.5 dB
- Typical single-carrier WCDMA performance, 960 MHz, 28 V, 7.5 dB PAR @ 0.01% CCDF,
 - Output power = 63 W
 - Efficiency = 33%
 - Gain = 19.5 dB
 - ACPR = -35 dBc @ 3.84 MHz
- Capable of handling 10:1 VSWR @ 28 V, 220 W (CW) output power
- Integrated ESD protection
- Low thermal resistance
- Pb-free and RoHS compliant

RF Characteristics

Two-carrier WCDMA Specifications (tested in Wolfspeed test fixture)

$V_{DD} = 28\text{ V}$, $I_{DQ} = 2150\text{ mA}$, $P_{OUT} = 60\text{ W avg}$, $f = 960\text{ MHz}$, 3GPP signal, 3.84 MHz channel bandwidth, 8 dB peak/average @ 0.01% CCDF, 10 MHz spacing

Characteristic	Symbol	Min	Typ	Max	Unit
Gain	G_{ps}	18	19	—	dB
Drain Efficiency	η_D	28	29	—	%
Intermodulation Distortion	IMD	—	-34	-33	dBc

All published data at $T_{CASE} = 25^\circ\text{C}$ unless otherwise indicated

ESD: Electrostatic discharge sensitive device—observe handling precautions!

DC Characteristics

Characteristic	Conditions	Symbol	Min	Typ	Max	Unit
Drain-Source Breakdown Voltage	$V_{GS} = 0\text{ V}$, $I_{DS} = 10\text{ mA}$	$V_{(BR)DSS}$	65	—	—	V
Drain Leakage Current	$V_{DS} = 28\text{ V}$, $V_{GS} = 0\text{ V}$	I_{DSS}	—	—	1	μA
	$V_{DS} = 63\text{ V}$, $V_{GS} = 0\text{ V}$	I_{DSS}	—	—	10	μA
Gate Leakage Current	$V_{GS} = 10\text{ V}$, $V_{DS} = 0\text{ V}$	I_{GSS}	—	—	1	μA
On-State Resistance	$V_{GS} = 10\text{ V}$, $V_{DS} = 0.1\text{ V}$	$R_{DS(on)}$	—	0.05	—	Ω
Operating Gate Voltage	$V_{DS} = 28\text{ V}$, $I_{DQ} = 2150\text{ mA}$	V_{GS}	2.5	3.9	4.5	V

Maximum Ratings

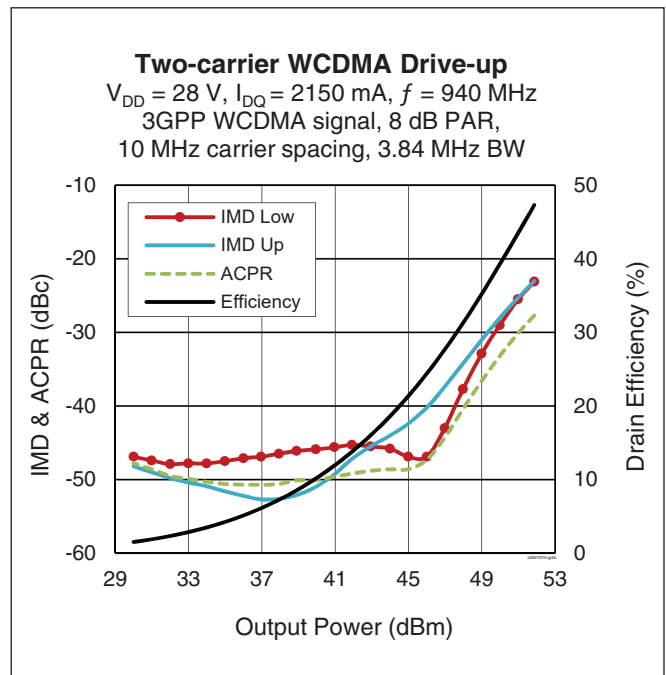
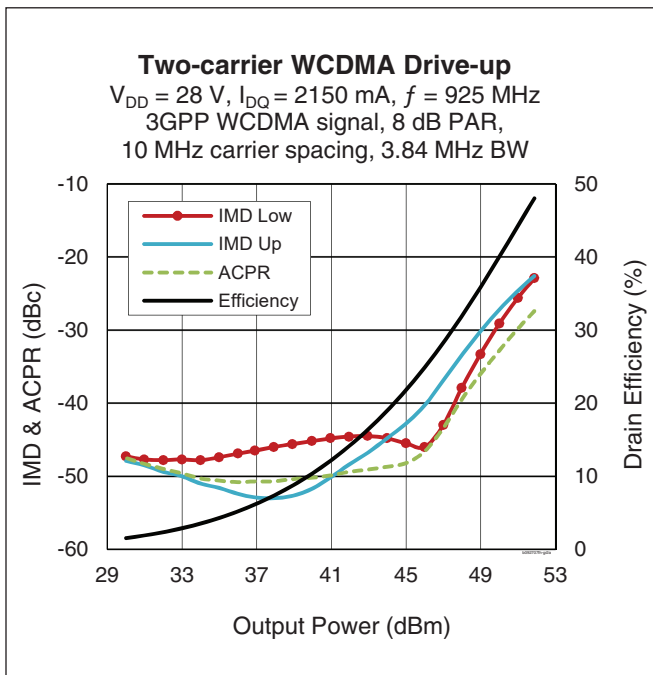
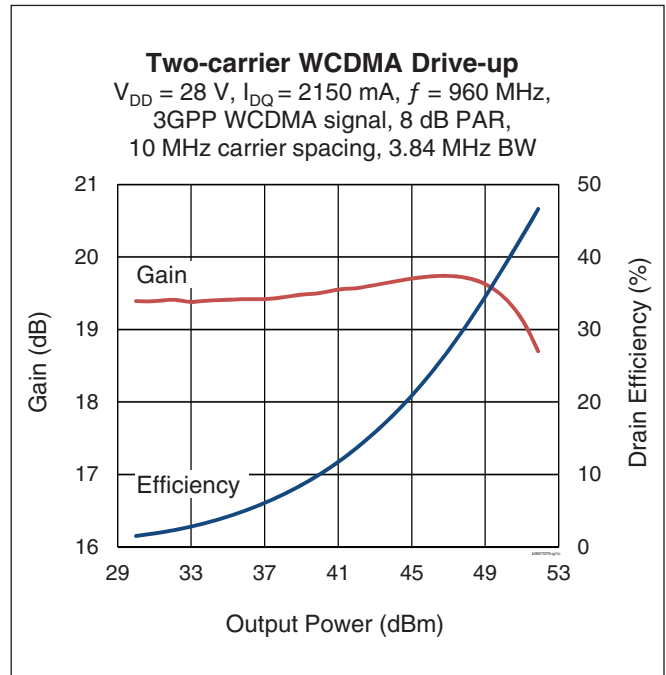
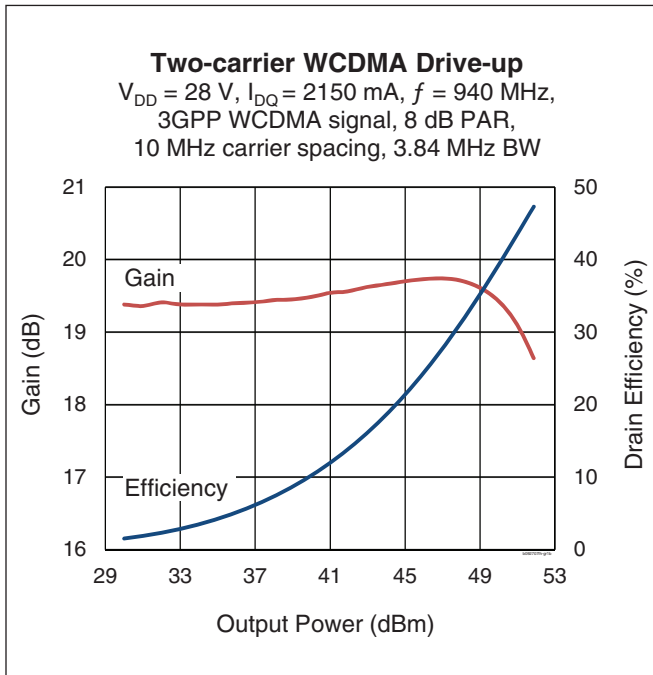
Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DSS}	65	V
Gate-Source Voltage	V_{GS}	-6 to +10	V
Junction Temperature	T_J	200	$^{\circ}\text{C}$
Storage Temperature Range	T_{STG}	-40 to +150	$^{\circ}\text{C}$
Thermal Resistance ($T_{CASE} = 70^{\circ}\text{C}$, 220 W CW)	$R_{\theta JC}$	0.214	$^{\circ}\text{C/W}$

Ordering Information

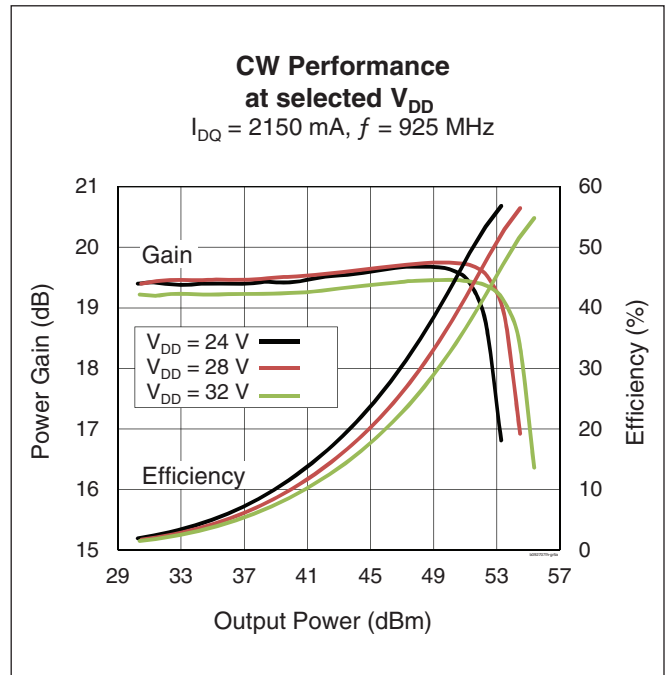
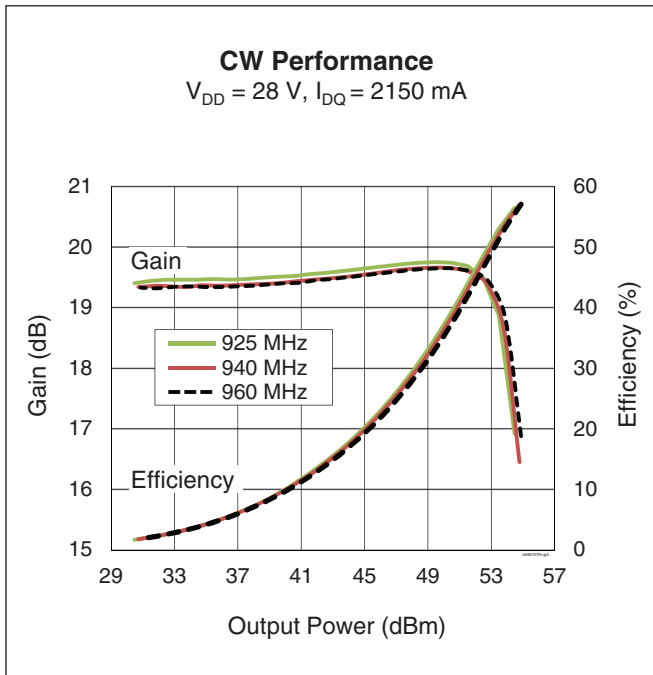
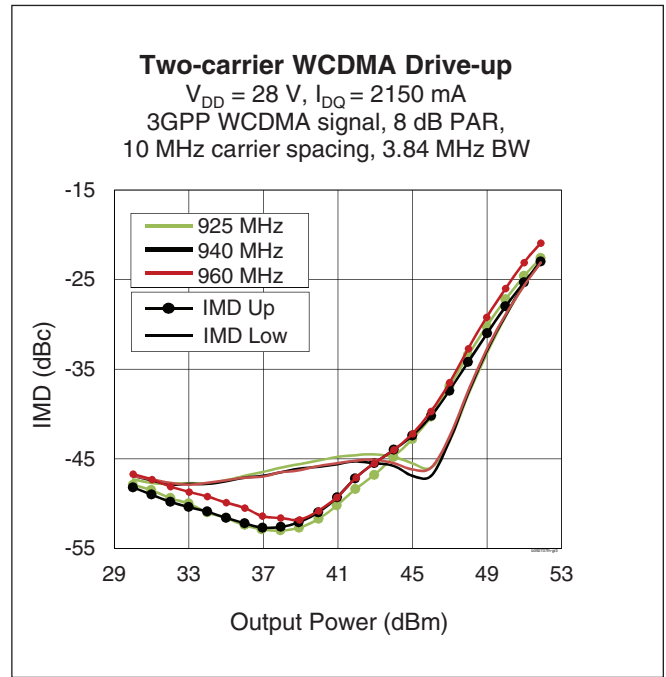
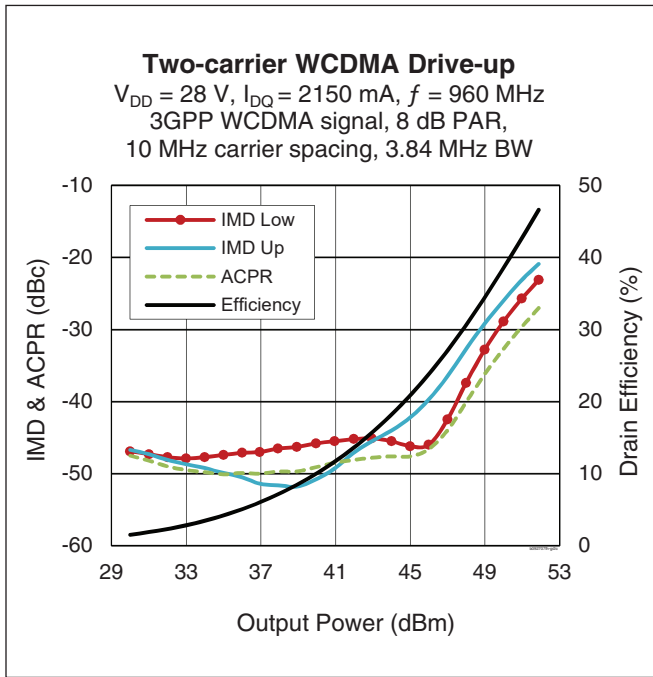
Type and Version	Order Code	Package and Description	Shipping
PTFB092707FH V1 R0	PTFB092707FH-V1-R0	H-37288L-4/2, earless flange	Tape & Reel, 50 pcs
PTFB092707FH V1 R250	PTFB092707FH-V1-R250	H-37288L-4/2, earless flange	Tape & Reel, 250 pcs



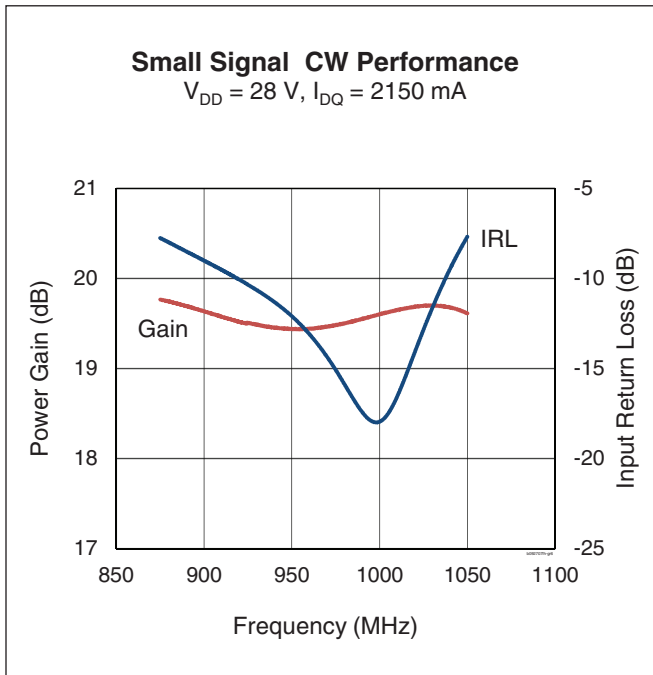
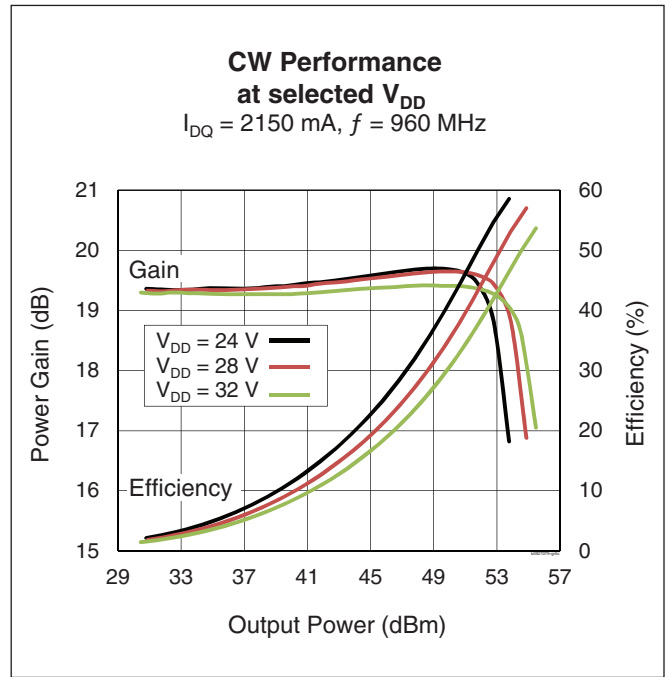
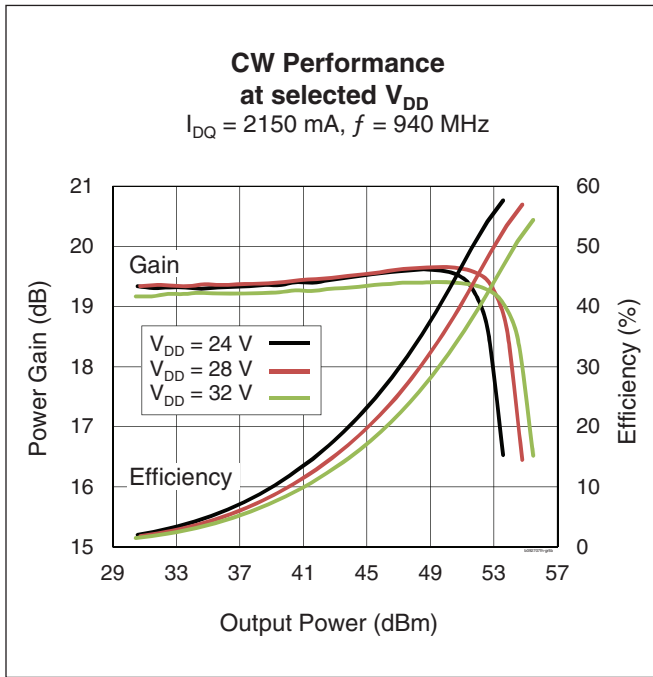
Typical Performance (data taken in an Wolfspeed test fixture)



Typical Performance (cont.)

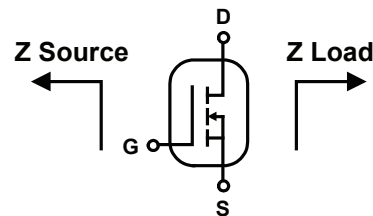


Typical Performance (cont.)



Broadband Circuit Impedance

Frequency MHz	Z Source Ω		Z Load Ω	
	R	jX	R	jX
900	1.52	-1.80	0.98	-1.65
920	1.55	-1.69	0.89	-1.54
940	1.59	-1.60	0.82	-1.42
960	1.63	-1.53	0.74	-1.29
980	1.65	-1.48	0.67	-1.16



Load Pull Performance

Pulsed CW signal: 10 μ sec, 10% duty cycle, 28 V, 2.0 A

Class AB		P _{1dB}									
		Max Output Power					Max PAE				
Freq [MHz]	Z _s [Ω]	Z _l [Ω]	Gain [dB]	P _{OUT} [dBm]	P _{OUT} [W]	PAE [%]	Z _l [Ω]	Gain [dB]	P _{OUT} [dBm]	P _{OUT} [W]	PAE [%]
920	1.62 - j2.25	0.88 - j1.37	17.3	54.26	267	42.9	2.16 - j0.22	20.8	52.02	159	62.1
940	1.80 - j2.54	0.76 - j1.49	17.0	54.38	274	41.4	2.38 - j0.50	20.9	51.87	154	61.8
960	1.73 - j2.59	0.73 - j1.46	17.4	54.38	274	41.4	2.09 - j0.64	20.8	52.02	159	60.3

Reference Circuit, tuned for 925 – 960 MHz

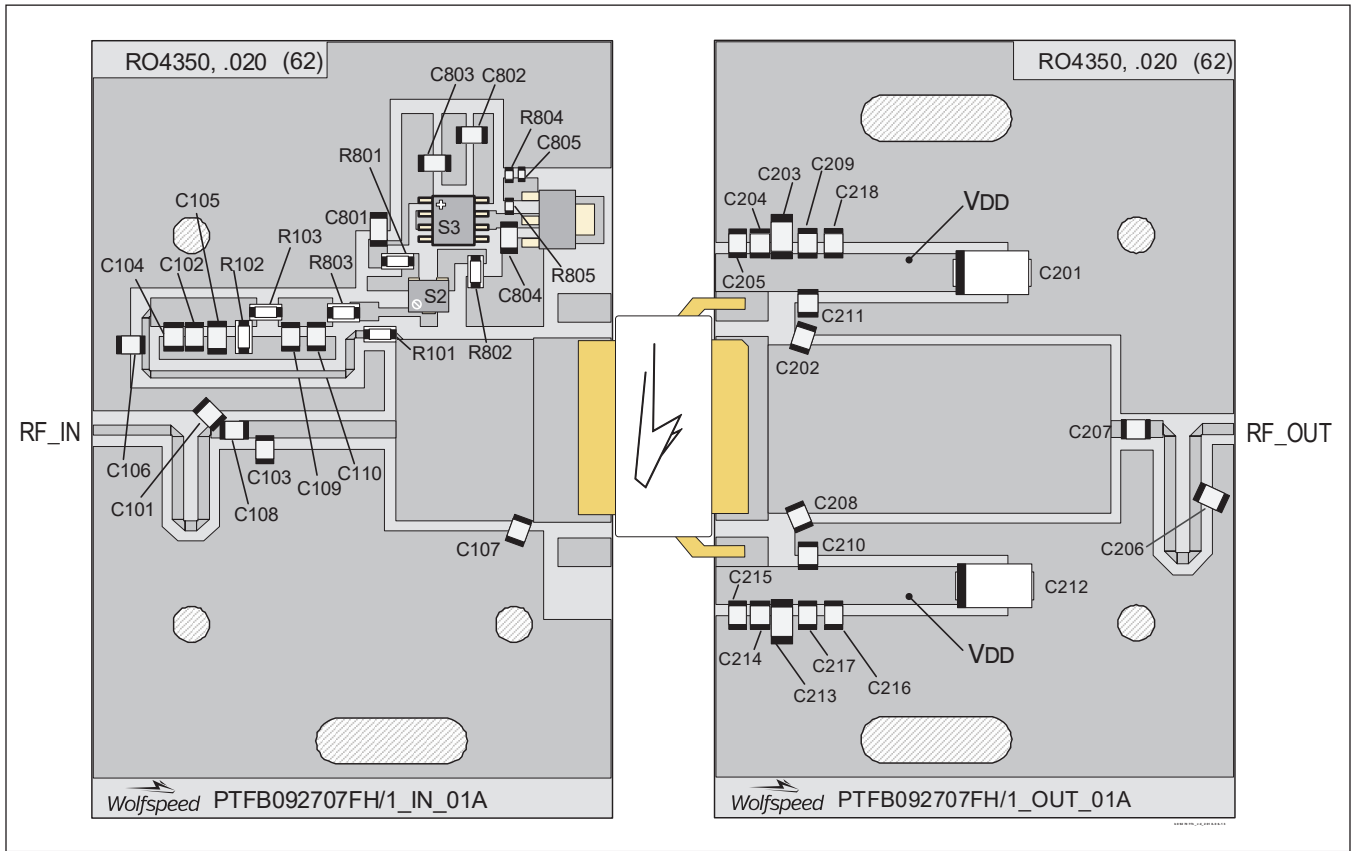
DUT PTFB092707FH V1

Reference Circuit Part No. LTN/PTFB092707FH V1

PCB Rogers 4350, 0.508 mm [.020"] thick, 2 oz. copper, $\epsilon_r = 3.66$

Find Gerber files for this reference fixture on the Wolfspeed Web site (www.wolfspeed.com/RF)

Reference Circuit (cont.)



Reference circuit assembly diagram (not to scale)

Assembly Information

Component	Description	Suggested Manufacturer	P/N
Input			
C101	Chip capacitor, 1 pF	ATC	ATC100B1R0CW500XB
C102	Chip capacitor, 0.002 μ F	ATC	ATC200B203MW50X
C103	Chip capacitor, 4.7 pF	ATC	ATC100B4R7CW500XB
C104	Chip capacitor, 33 pF	ATC	ATC100B330JW
C105	Capacitor 4.7 μ F	Nichicon	F931C475MAA
C106, C108	Chip capacitor, 56 pF	ATC	ATC100B560JT
C107	Chip capacitor, 12 pF	ATC	ATC100B120JW
C109	Chip capacitor, 4.7 pF	ATC	ATC100B4R7CT
C110	Chip capacitor, 0.01 μ F	ATC	ATC200B103MW50X
C801, C804	Chip capacitor, 0.1 μ F	Panasonic Electronic Components	ECJ-3VB1H104K
C802, C803, C805	Chip capacitor, 0.001 μ F	Panasonic	ECJ-1VB1H102K
R101, R801, R803	Resistor, 10 Ω	Panasonic Electronic Components	ERJ-8GEYJ100V
R102, R103	Resistor, 20 Ω	Panasonic Electronic Components	ERJ-8GEYJ200V
R802	Resistor, 1k Ω	Panasonic Electronic Components	ERJ-8GEYJ102V
R804	1.3k ohms	Panasonic Electronic Components	ERJ-3GEYJ132V
R805	1.2k ohms	Panasonic Electronic Components	ERJ-3GEYJ122V

(table cont. next page)



Reference Circuit (cont.)

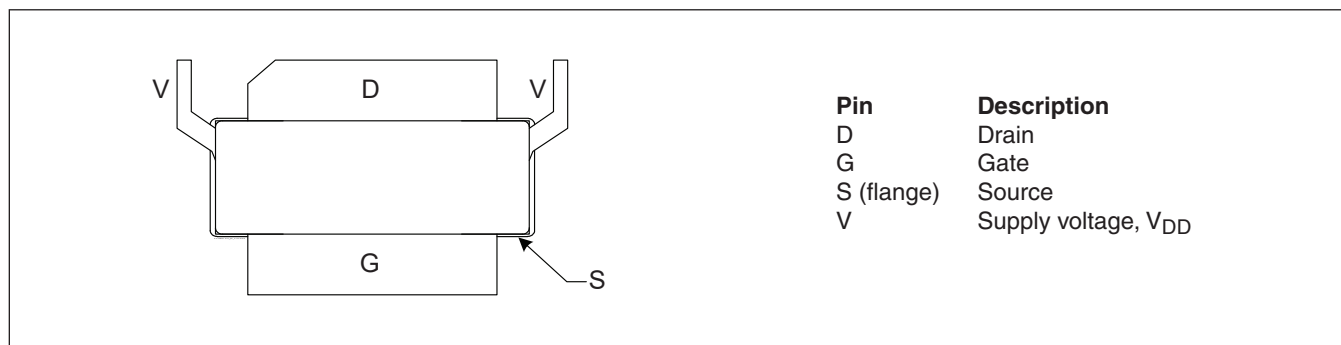
Assembly Information (cont.)

Component	Description	Suggested Manufacturer	P/N
S1	Transistor	Fairchild Semiconductor	BCP56-10
S2	Potentiometer, 2k Ω	Bourns Inc.	3224W-1-202E
S3	Voltage regulator	Fairchild Semiconductor	LM7805

Output

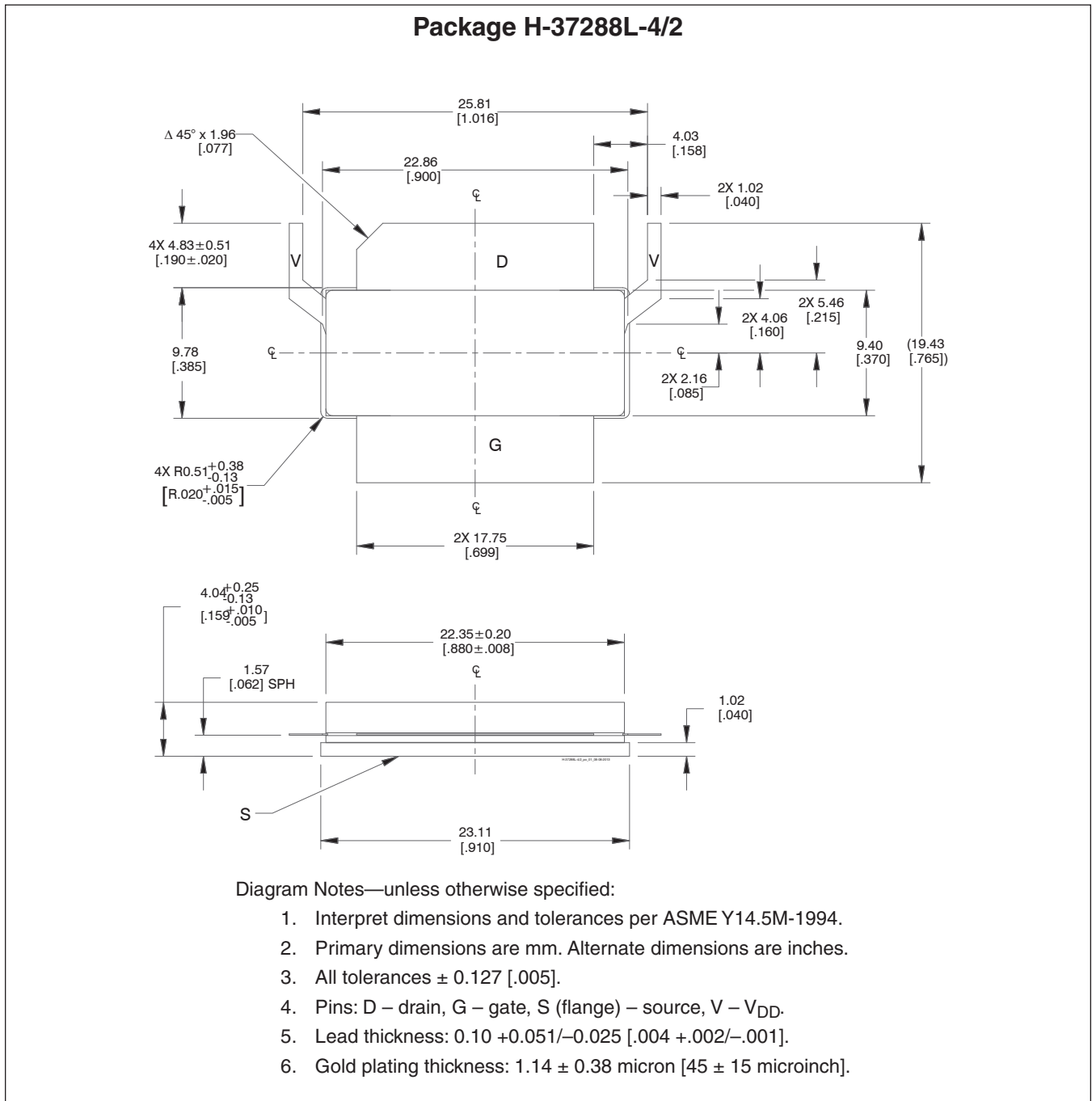
C201, C212	Chip capacitor, 10 μ F	Matsuo	281M5002106K
C202	Chip capacitor, 2.2 pF	ATC	ATC100B2R2CW
C203, C213	Ceramic capacitor, 1 μ F, 250 V	AVX Corporation	2225PC105KAT1A
C204, C205, C214, C215	Capacitor, 10 μ F	Taiyo Yuden	UMK325C7106MM-T
C206	Chip capacitor, 4.2 pF	ATC	ATC100B4R2CT
C207	Chip capacitor, 56 pF	ATC	ATC100B560JT
C208	Chip capacitor, 3.3 pF	ATC	ATC100B3R3CW
C209, C216, C217, C218	Ceramic capacitor, 4.7 μ F, 50 V	Murata Electronics North America	GRM32ER71H475KA88L
C210, C211	Capacitor, 10k pF	ATC	ATC200B103MW50X

Pinout Diagram (top view)



Lead connections for PTFB092707FH

Package Outline Specifications



Revision History

Revision	Date	Data Sheet Type	Page	Subjects (major changes since last revision)
01	2011-03-25	Advance	All	New product, proposed only
02	2014-02-25	Advance	All	Package changed, revised all data
03	2014-04-01	Production	All	Data Sheet now represents production-released product specifications, including reference circuit and performance information
03.1	2016-06-10	Production	2	Updated ordering code to R0
04	2018-06-13	Production	All	Converted to Wolfspeed Data Sheet

For more information, please contact:

4600 Silicon Drive
 Durham, North Carolina, USA 27703
www.wolfspeed.com/RF

Sales Contact
RFSales@wolfspeed.com

RF Product Marketing Contact
RFMarketing@wolfspeed.com
 919.407.7816

Notes

Disclaimer

Specifications are subject to change without notice. Cree, Inc. believes the information contained within this data sheet to be accurate and reliable. However, no responsibility is assumed by Cree for any infringement of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of Cree. Cree makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose. "Typical" parameters are the average values expected by Cree in large quantities and are provided for information purposes only. These values can and do vary in different applications and actual performance can vary over time. All operating parameters should be validated by customer's technical experts for each application. Cree products are not designed, intended or authorized for use as components in applications intended for surgical implant into the body or to support or sustain life, in applications in which the failure of the Cree product could result in personal injury or death or in applications for planning, construction, maintenance or direct operation of a nuclear facility.

Компания «Life Electronics» занимается поставками электронных компонентов импортного и отечественного производства от производителей и со складов крупных дистрибьюторов Европы, Америки и Азии.

С конца 2013 года компания активно расширяет линейку поставок компонентов по направлению коаксиальный кабель, кварцевые генераторы и конденсаторы (керамические, пленочные, электролитические), за счёт заключения дистрибьюторских договоров

Мы предлагаем:

- Конкурентоспособные цены и скидки постоянным клиентам.
- Специальные условия для постоянных клиентов.
- Подбор аналогов.
- Поставку компонентов в любых объемах, удовлетворяющих вашим потребностям.
- Приемлемые сроки поставки, возможна ускоренная поставка.
- Доставку товара в любую точку России и стран СНГ.
- Комплексную поставку.
- Работу по проектам и поставку образцов.
- Формирование склада под заказчика.
- Сертификаты соответствия на поставляемую продукцию (по желанию клиента).
- Тестирование поставляемой продукции.
- Поставку компонентов, требующих военную и космическую приемку.
- Входной контроль качества.
- Наличие сертификата ISO.

В составе нашей компании организован Конструкторский отдел, призванный помогать разработчикам, и инженерам.

Конструкторский отдел помогает осуществить:

- Регистрацию проекта у производителя компонентов.
- Техническую поддержку проекта.
- Защиту от снятия компонента с производства.
- Оценку стоимости проекта по компонентам.
- Изготовление тестовой платы монтаж и пусконаладочные работы.



Тел: +7 (812) 336 43 04 (многоканальный)

Email: org@lifeelectronics.ru